



AMP2030 SOLID STATE HIGH POWER AMPLIFIER



FEATURES

- Class AB linear GaN design
- Instantaneous ultra-wide bandwidth
- Rack mounted system
- Designed for broadband EMI/RFI, Lab, Comm. and EW applications
- Suitable for all single channel modulation standards
- Built-in protection circuits
- High reliability and ruggedness

ELECTRICAL SPECIFICATIONS: 25°C, 50Ω

Parameter	Specification	Notes
Operating Frequency Range	1.0 - 6.0 GHz	
Power Output @ Psat	300 Watt Min	
Power Output @ P1dB GCP	200 Watt Min	CW
Power Gain	53 dB Min	
Power Gain Flatness	4 dB p-p Max	Constant input power
Gain Variation Over Temperature	±2.0 dB Max	
Input / Output Return Loss	-10 dB Max	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	-30 dBc Typ	43dBm/Tone, Δ = 1MHz
Harmonics	-20 dBc Typ	At rated output
Spurious	-60 dBc Max	Non-harmonic
Operating Voltage	180 - 240 VAC	
Power Consumption	2500 Watt Max	At rated output
Input Power Protection	+5 dBm Max	<10 Sec without damage
Load VSWR Protection	10 : 1 Max	<1 minute at rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	425 x 222 x 560 mm	5U - excluding handles
Weight	45 Kg. Max	
RF Connectors In/Out	Type-N Female	
AC Power	IEC 60320-C14 / 9-Pin D-Sub	Or equivalent
Cooling	Built in Fan Cooling	Variable speed
OPTIONAL: Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485, USB Optional GPIB Interface	Optional Remote Bluetooth application

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OUTLINE DRAWING

